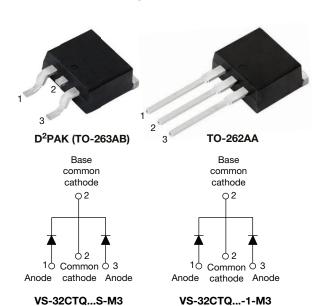
# VS-32CTQ...S-M3, VS-32CTQ...-1-M3 Series

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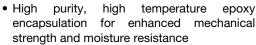
# High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 15 A				
$V_{R}$	25 V, 30 V				
V <sub>F</sub> at I <sub>F</sub>	0.40 V				
I <sub>RM</sub> typ.	97 mA at 125°C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	13 mJ				
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

### **FEATURES**

- 150 °C T<sub>J</sub> operation
- · Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **DESCRIPTION**

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNITS								
I <sub>F(AV)</sub>	Rectangular waveform	30	A						
V <sub>RRM</sub>		25, 30	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	900	А						
V <sub>F</sub>	15 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.40	V						
T <sub>J</sub>	Range	-55 to +150	°C						

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-32CTQ025S-M3 VS-32CTQ025-1-M3	VS-32CTQ030S-M3 VS-32CTQ030-1-M3	UNITS			
Maximum DC reverse voltage	$V_{R}$	25	30	V			
Maximum working peak reverse voltage	$V_{RWM}$	25	30	V			



# VS-32CTQ...S-M3, VS-32CTQ...-1-M3 Series

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ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 115 °C	30				
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse Following any rated load		900	Α		
surge current See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse condition and with rated V <sub>RRM</sub> applied		250			
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.20 A, L = 11.10 mH		13	mJ		
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by T <sub>J</sub> maxim	3	Α			

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		15 A	T.ı = 25 °C	0.49	V		
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	30 A	IJ=25 C	0.58			
See fig. 1	VFM (1)	15 A	T <sub>.1</sub> = 125 °C	0.40			
		30 A	11 = 125 0	0.53			
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	1.75	mA		
		T <sub>J</sub> = 125 °C	V <sub>R</sub> = nateu V <sub>R</sub>	145			
Typical reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	97	mA		
Threshold voltage	V <sub>F(TO)</sub>	T - T movimum		0.233	V		
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		9.09	mΩ		
Maximum junction capacitance per leg	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range 100 kHz to 1 MHz), 25 °C		1300	pF		
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm	8.0	nΗ			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs		

### Note

 $<sup>^{(1)}\,</sup>$  Pulse width  $<300~\mu s,~duty~cycle < 2~\%$ 

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C		
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation See fig. 4	3.25	°C/W		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	C/VV		
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
			Case style D <sup>2</sup> PAK (TO-263AB)	32CT0	Q025S		
Marking device			Case style D-PAK (TO-263AB)	32CT0	Q030S		
			Consistua TO 262AA	32CTC	025-1		
			Case style TO-262AA	32CTC	32CTQ030-1		



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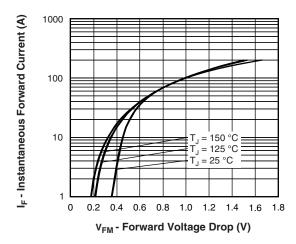


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

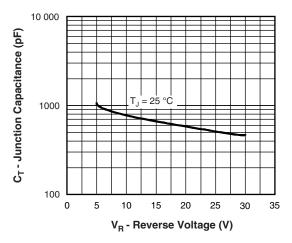


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

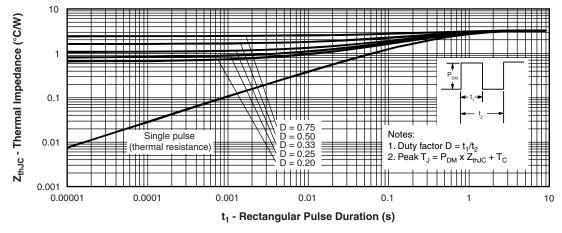


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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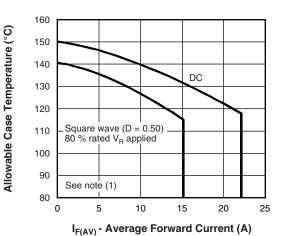


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

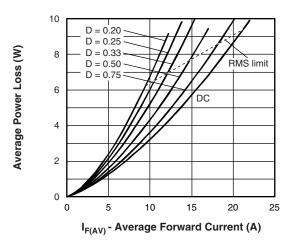


Fig. 6 - Forward Power Loss Characteristics

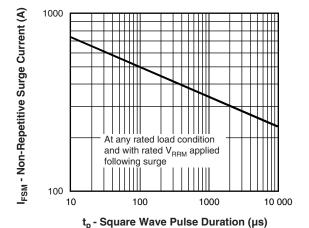


Fig. 7 - Maximum Non-Repetitive Surge Current

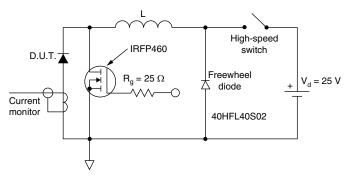


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

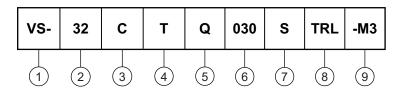
 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$ 

# VS-32CTQ...S-M3, VS-32CTQ...-1-M3 Series

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### **ORDERING INFORMATION TABLE**

### **Device code**



1 - Vishay Semiconductors product

2 - Current rating (30 A)

**3** - Circuit configuration: C = common cathode

**4** - T = TO-220

5 - Schottky "Q" series

- Voltage ratings — 025 = 25 V 030 = 30 V

7 - • S = D<sup>2</sup>PAK (TO-263AB)

• -1 = TO-262AA

8 - • None = tube

• TRL = tape and reel (left oriented - for D<sup>2</sup>PAK (TO-263AB) only)

• TRR = tape and reel (right oriented - for D<sup>2</sup>PAK (TO-263AB) only)

9 - -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-32CTQ025S-M3	50	1000	Antistatic plastic tubes				
VS-32CTQ025STRR-M3	800	800	13" diameter reel				
VS-32CTQ025STRL-M3	800	800	13" diameter reel				
VS-32CTQ025-1-M3	50	1000	Antistatic plastic tubes				
VS-32CTQ030S-M3	50	1000	Antistatic plastic tubes				
VS-32CTQ030STRR-M3	800	800	13" diameter reel				
VS-32CTQ030STRL-M3	800	800	13" diameter reel				
VS-32CTQ030-1-M3	50	1000	Antistatic plastic tubes				

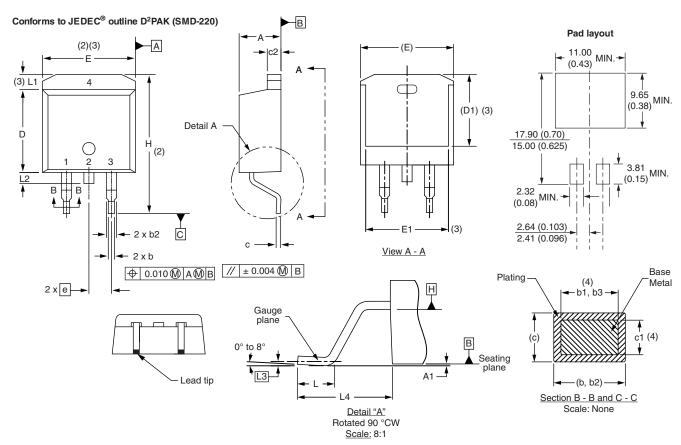
LINKS TO RELATED DOCUMENTS						
Dimensions D <sup>2</sup> PAK (TO-263AB) <u>www.vishay.com/doc?96164</u>						
Diffierisions	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444				
Fait marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				



# Vishay Semiconductors

# D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



CVMPOL	SYMBOL MILLIME		INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS		INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

- $^{(1)}$  Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

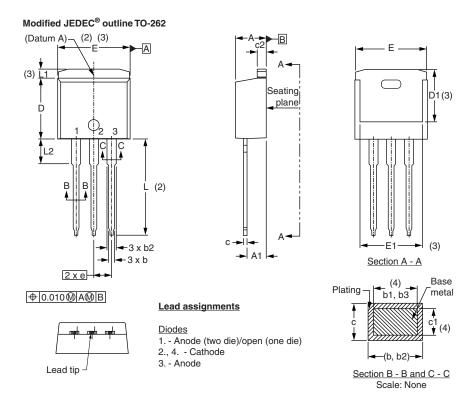




# Vishay Semiconductors

# **TO-262**

### **DIMENSIONS** in millimeters and inches



CVMPOL	MILLIM	IETERS	INC	HES	NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.36	3.71	0.132	0.146	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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